

SG2013J-883B Information

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For Reference Only

Part Number SG2013J-883B

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - Arrays

Description TRANS 7NPN DARL 50V 0.6A 16JDIP

Package -

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SG2013J-883B Specifications

Manufacturer Part Number	SG2013J-883B
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays
Package	-
Series	-
Transistor Type	7 NPN Darlington
Current - Collector (Ic) (Max)	600mA
Voltage - Collector Emitter Breakdown (Max)	50V
Vce Saturation (Max) @ Ib, Ic	1.9V @ 600μA, 500mA
Current - Collector Cutoff (Max)	-
DC Current Gain (hFE) (Min) @ Ic, Vce	900 @ 500mA, 2V
Power - Max	-
Frequency - Transition	-
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Package / Case	-
Supplier Device Package	16-CDIP
	Report errors?

SG2013J-883B Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SG2013J-883B Payment Methods





















SG2013J-883B Shipping Methods













If you have any question about SG2013J-883B, please do not hesitate to contact us!

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